



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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NSVJ3557SA3

N-Channel JFET 15V, 10 to 32mA, 35mS

Automotive JFET designed for compact and efficient designs and including high gain performance. AEC-Q101 qualified JFET and PPAP capable suitable for automotive applications.

Features

- Large $|y_{fs}|$
- Small Ciss
- This small package enables sets to be smaller and thinner
- Ultralow noise figure
- Pb-Free and RoHS compliance
- AEC-Q101 qualified and PPAP capable

Typical Applications

- AM Tuner RF Amplifier
- Low Noise Amplifier

SPECIFICATIONS

ABSOLUTE MAXIMUM RATINGS at $T_a = 25^\circ\text{C}$ (Note 1)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V_{DSX}	15	V
Gate-to-Drain Voltage	V_{GDS}	-15	V
Gate Current	I_G	10	mA
Drain Current	I_D	50	mA
Allowable Power Dissipation	P_D	200	mW
Operating Junction and Storage Temperature	T_J, T_{Stg}	-55 to+150	$^\circ\text{C}$

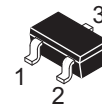
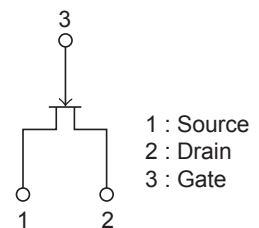
Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



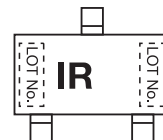
ON Semiconductor®

www.onsemi.com

ELECTRICAL CONNECTION N-Channel



SC-59 / CP3



NSVJ3557SA3T1G

ORDERING INFORMATION

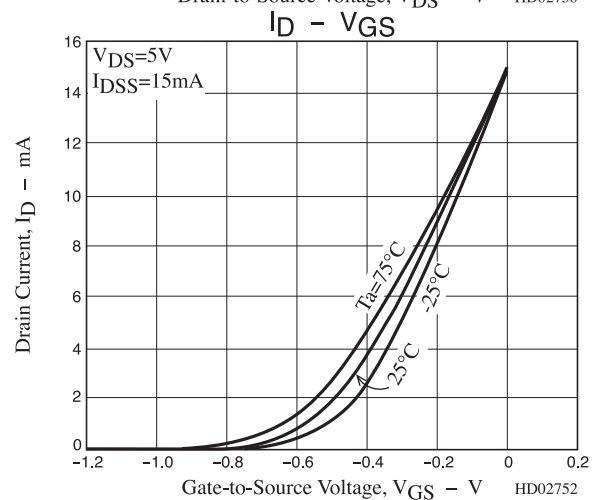
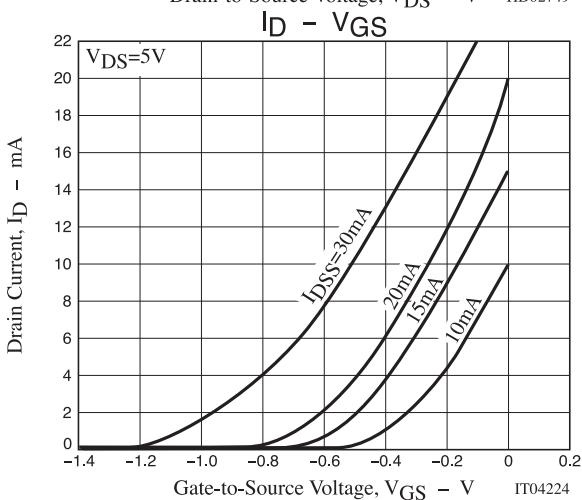
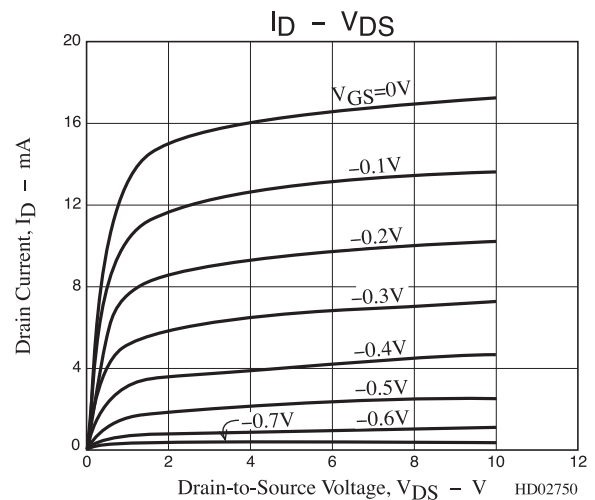
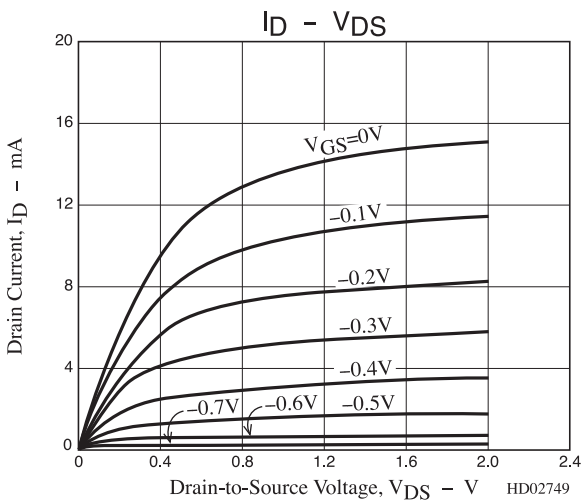
See detailed ordering and shipping information on page 5 of this data sheet

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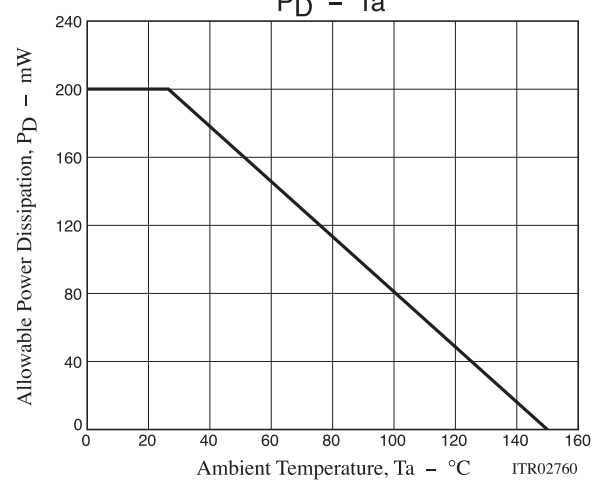
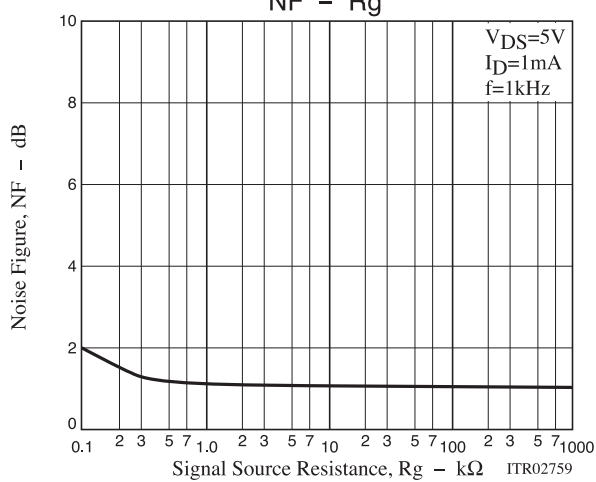
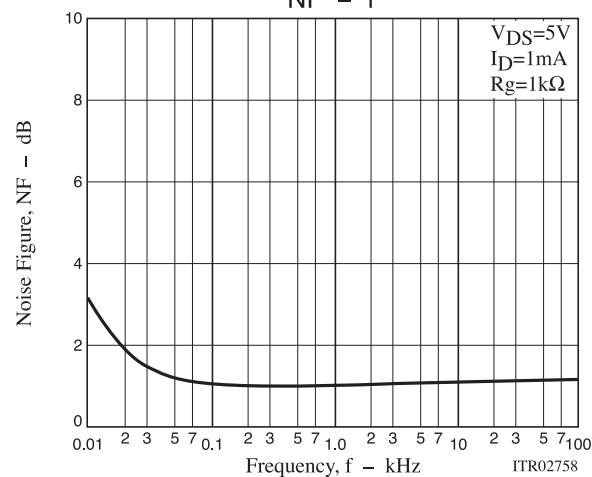
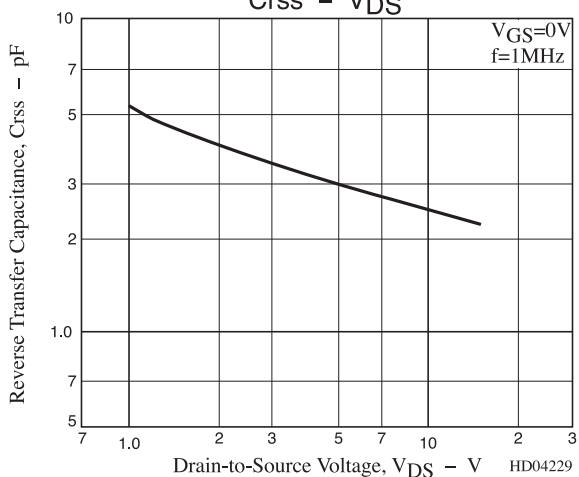
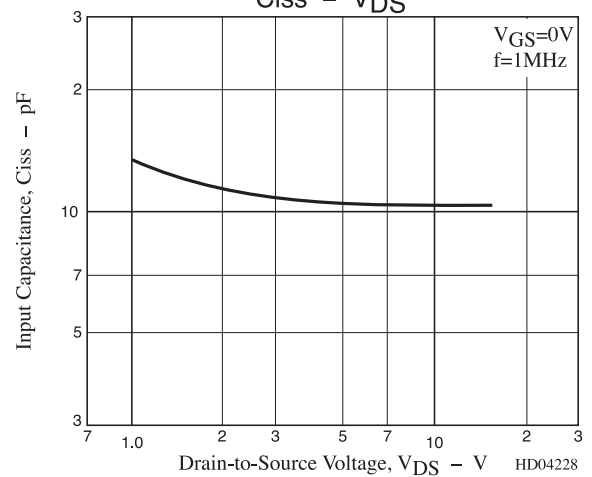
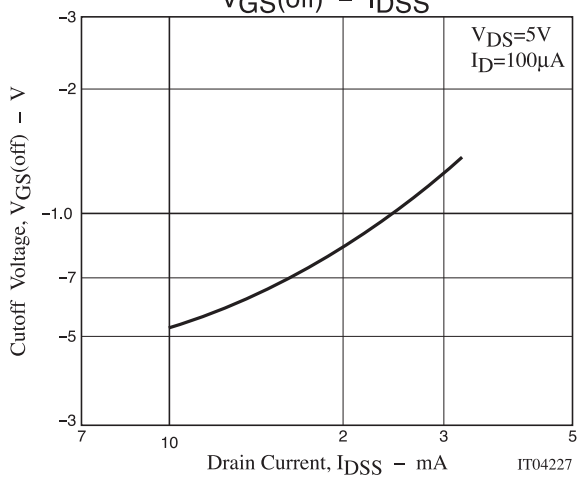
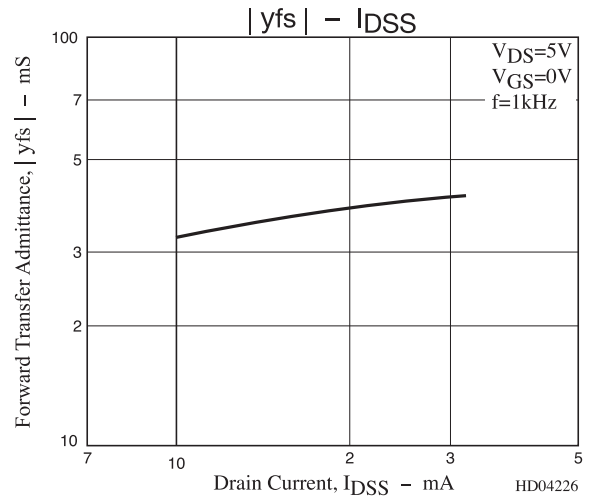
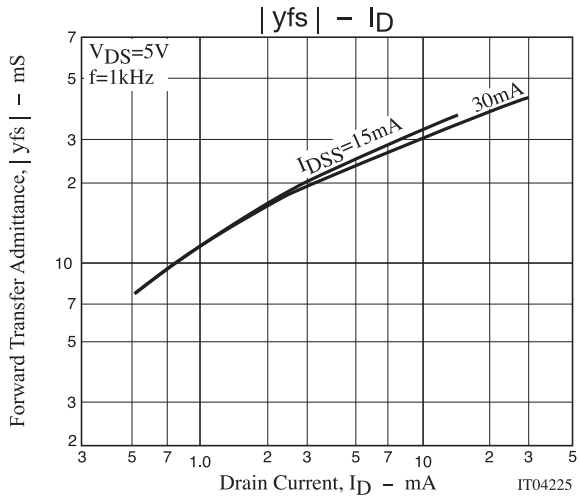
ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 2)

Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Gate-to-Drain Breakdown Voltage	$V_{(BR)GDS}$	$I_G = -10\mu A, V_{DS} = 0V$	-15			V
Gate Cutoff Current	I_{GSS}	$V_{GS} = -10V, V_{DS} = 0V$			-1	nA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 5V, I_D = 100\mu A$	-0.3	-0.7	-1.5	V
Drain Current	I_{DSS}	$V_{DS} = 5V, V_{GS} = 0V$	10		32	mA
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 5V, V_{GS} = 0V, f = 1kHz$	24	35		mS
Input Capacitance	C_{iss}	$V_{DS} = 5V, V_{GS} = 0V, f = 1MHz$		10		pF
Reverse Transfer Capacitance	C_{rss}			2.9		pF
Noise Figure	NF	$V_{DS} = 5V, R_g = 1k\Omega, I_D = 1mA, f = 1kHz$		1		dB

Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



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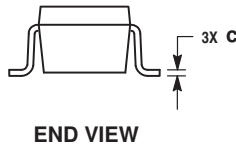
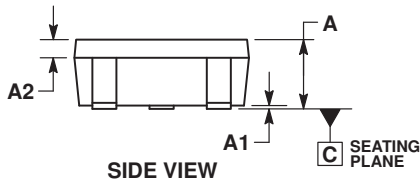
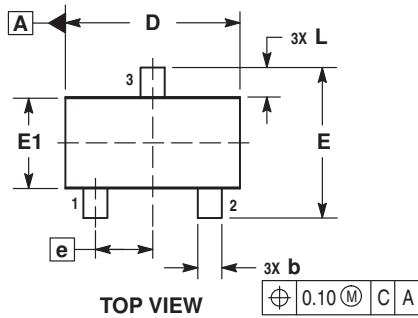


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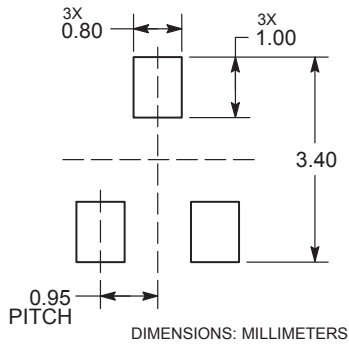
PACKAGE DIMENSIONS

unit : mm

SC-59 / CP3
CASE 318BJ
ISSUE O



RECOMMENDED SOLDERING FOOTPRINT*

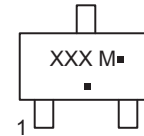


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER SIDE.
4. DIMENSIONS D AND E1 ARE MEASURED AT THE OUTERMOST EXTREME OF THE PLASTIC BODY.
5. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 AND 0.20 FROM THE TIP.

MILLIMETERS		
DIM	MIN	MAX
A	0.95	1.35
A1	0.00	0.10
A2	0.20	0.40
b	0.35	0.50
c	0.10	0.20
D	2.75	3.05
E	2.30	2.70
E1	1.35	1.65
e	0.95 BSC	
L	0.35	0.75

GENERIC MARKING DIAGRAM



- XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NSVJ3557SA3

ORDERING INFORMATION

Device	Marking	Package	Shipping
NSVJ3557SA3T1G	IR	SC-59 3-Lead / CP3 (Pb-Free)	3,000 / Tape & Reel

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

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